

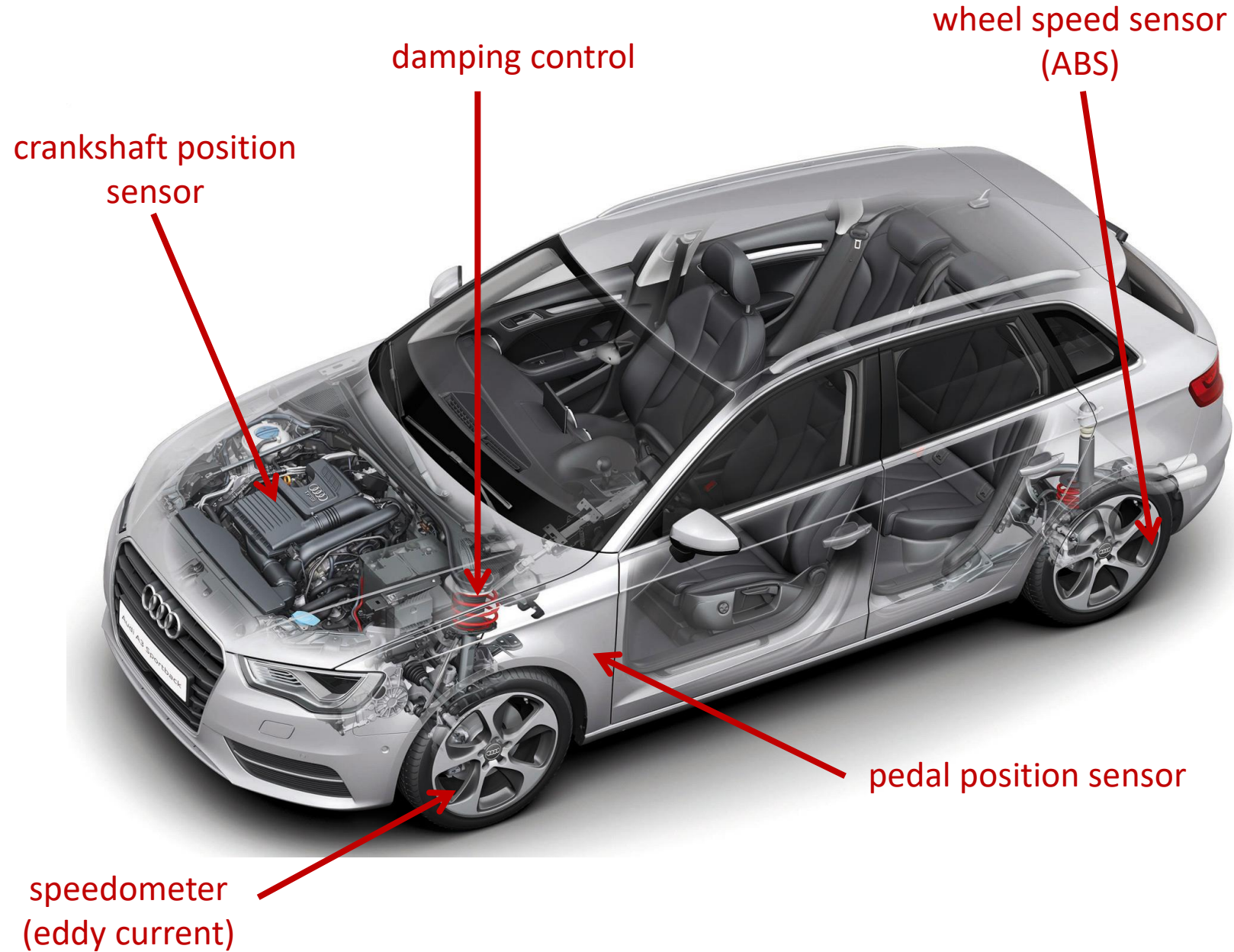


**Sensing, Computing, Actuating**

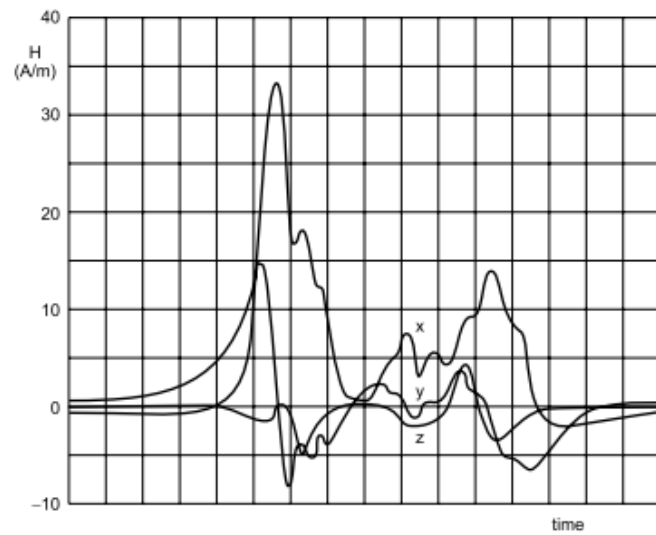
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# INDUCTIVE SENSORS

(Chapter 2.5, 2.6, 2.10, 5.4)







		Quantity			
		Position, distance, displacement	Flow rate / Point velocity	Force	Temperature
S e n s o r  t y p e	Resistive	Magnetoresistor	Thermistor	Strain gage	RTD
		Potentiometer			Thermistor
	Capacitive	Differential capacitor		Capacitive strain gage	Capacitor
	Inductive and electro-magnetic	Eddy currents	LVDT	Load cell + LVDT	LVDT
		Hall effect		Magnetostriction	
		LVDT			
		Magnetostriction			
	Self-generating		Thermal transport + thermocouple	Piezoelectric sensor	Pyroelectric sensor
					Thermocouple
	PN junction	Photoelectric sensor			Diode
				Bipolar transistor	

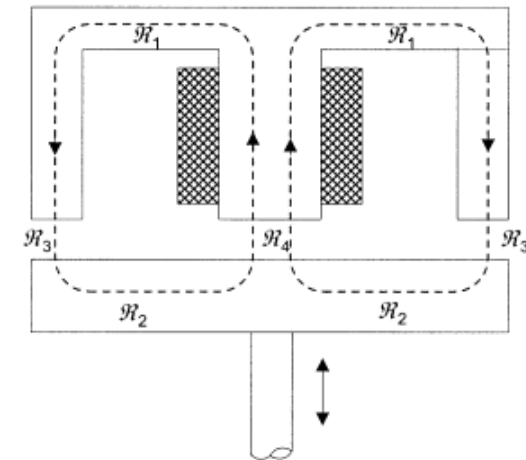
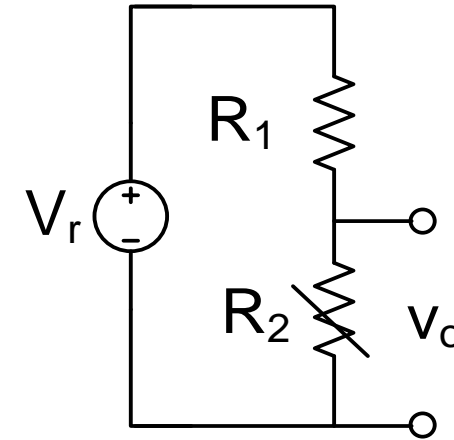
- reactance variation sensors (capacitive and inductive sensors)
  - typically require no physical contact
  - exert minimal mechanical loading

- **electrical circuit** may offer resistance to charge flow
  - resistor:  $R$
  - resistor dissipates electrical energy
  - current follows path of least resistance
  - total resistance

$$R_{tot} = R_1 + R_2$$

- **magnetic circuit** may offer reluctance to magnetic flux
  - reluctance:  $\mathfrak{R}$
  - reluctant circuit stores magnetic energy
  - magnetic flux follows path of least reluctance
  - total reluctance computed in similar way as resistance in electrical circuit

$$\mathfrak{R}_{tot} = \frac{\mathfrak{R}_1}{2} + \frac{\mathfrak{R}_2}{2} + \frac{\mathfrak{R}_3}{2} + \mathfrak{R}_4$$



- reluctance depends on physical properties of the device

$$\mathfrak{R} = \frac{1}{\mu\mu_0} \frac{l}{A}$$

- $l$  – length of the device
- $A$  – cross-sectional area
- $\mu_0$  – permeability of free space ( $4 \times 10^{-7}$  H/m)
- $\mu$  – relative permeability of the material
  - “soft” ferromagnetic material (typically 1000 to 10000)
  - permeability of air (approx. 1)
- options to vary reluctance
  - modify length  $l$  (variable gap sensor)
  - modify magnetic permeability  $\mu$  (moving core sensor)
  - modify cross-sectional area  $A$  (not frequently used)

- reluctance depends on physical properties of the device

$$\mathfrak{R} = \frac{1}{\mu\mu_0} \frac{l}{A}$$

- sensor requires conversion of magnetic signal to electric signal

- Faraday's law relates magnetic reluctance to electric current

$$v = \frac{N^2}{\mathfrak{R}} \frac{di}{dt} = L \frac{di}{dt}$$

- change in reluctance changes output voltage

- self-inductance L and reluctance are related:  $L = \frac{N^2}{\mathfrak{R}}$

- device can also be used as sensor without changing reluctance

- changing magnetic field causes electrons to move

- induces additional (eddy) current (eddy current sensor)



- what is the output voltage (in terms of  $x$ ) of a sensor with  $N$  windings?

$$\left. \begin{aligned} \mathfrak{R}_{core} &= \frac{l_{core}}{\mu_{core}\mu_0 A}, \quad \mathfrak{R}_{object} = \frac{l_{object}}{\mu_{object}\mu_0 A}, \quad \mathfrak{R}_{air} = \frac{x}{\mu_{air}\mu_0 A} \\ \mathfrak{R}_{total} &= \mathfrak{R}_{core} + \mathfrak{R}_{object} + 2 \cdot \mathfrak{R}_{air} \end{aligned} \right\} \Rightarrow \mathfrak{R}_{total} = \frac{l_{core}}{\mu_{core}\mu_0 A} + \frac{l_{object}}{\mu_{object}\mu_0 A} + \frac{2x}{\mu_{air}\mu_0 A}$$

- reluctance of core and object are constant

$$\mathfrak{R}_0 = \frac{l_{core}}{\mu_{core}\mu_0 A} + \frac{l_{object}}{\mu_{object}\mu_0 A}$$

- reluctance of the circuit

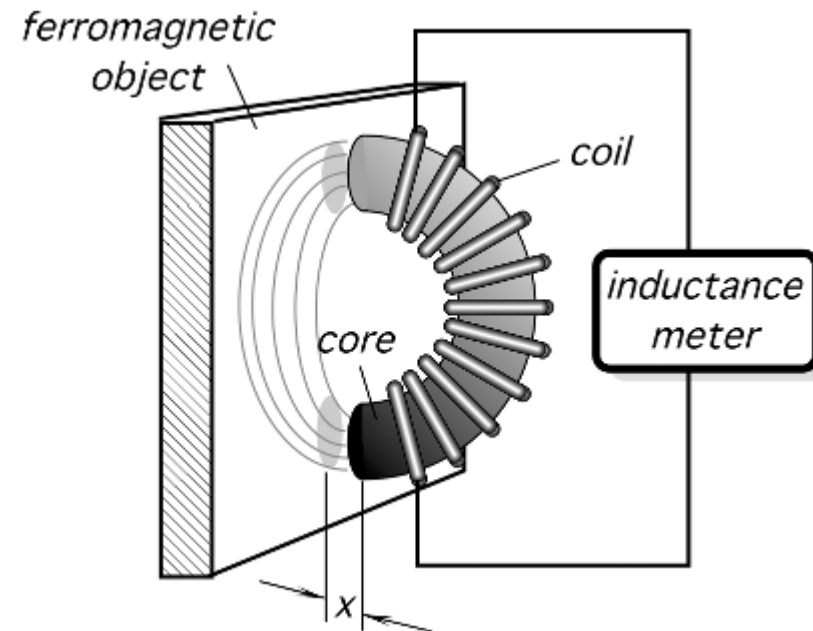
$$\mathfrak{R}_{total} = \mathfrak{R}_0 + \frac{2x}{\mu_{air}\mu_0 A} = \mathfrak{R}_0 + kx$$

- self-inductance of the circuit

$$L = \frac{N^2}{\mathfrak{R}_{total}} = \frac{N^2}{\mathfrak{R}_0 + kx}$$

- output voltage of the sensor

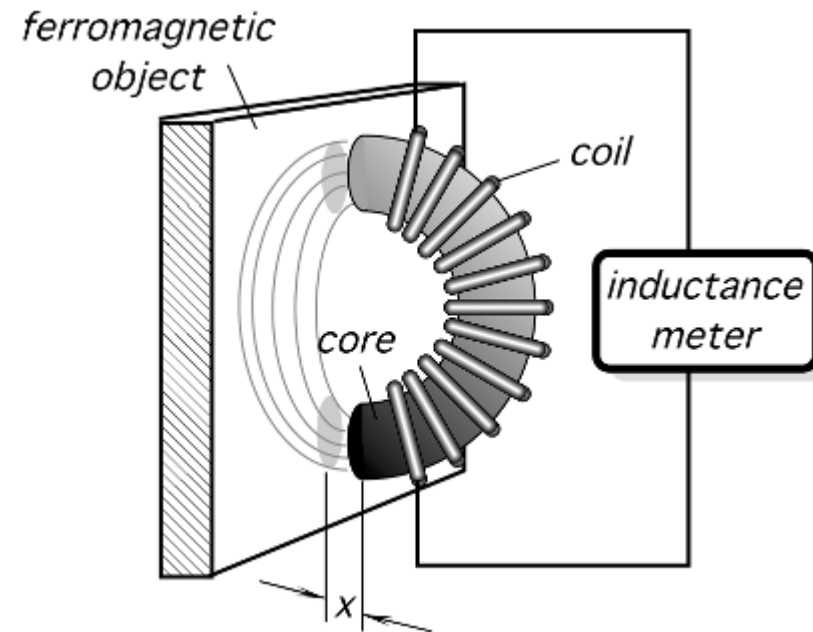
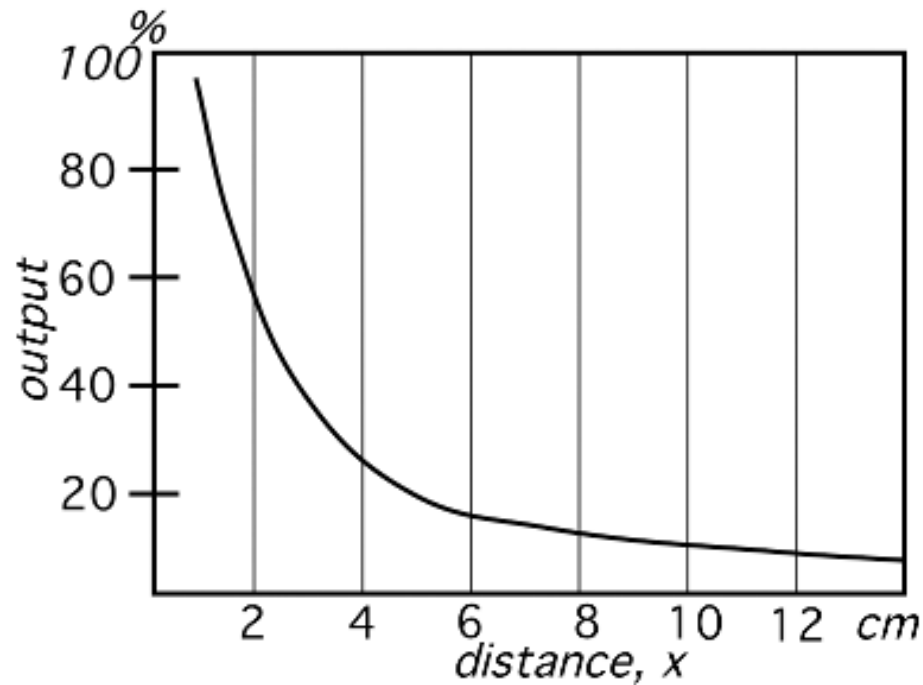
$$v = L \frac{di}{dt} = \frac{N^2}{\mathfrak{R}_0 + kx} \frac{di}{dt}$$



- output voltage of the sensor

$$v = L \frac{di}{dt} = \frac{N^2}{\mathfrak{R}_0 + kx} \frac{di}{dt}$$

- highly non-linear relation between output and displacement  $x$
- use of sensor limited to proximity sensor



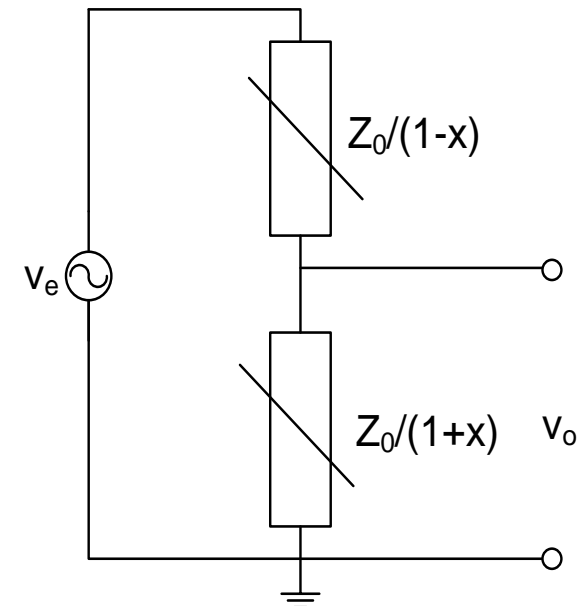
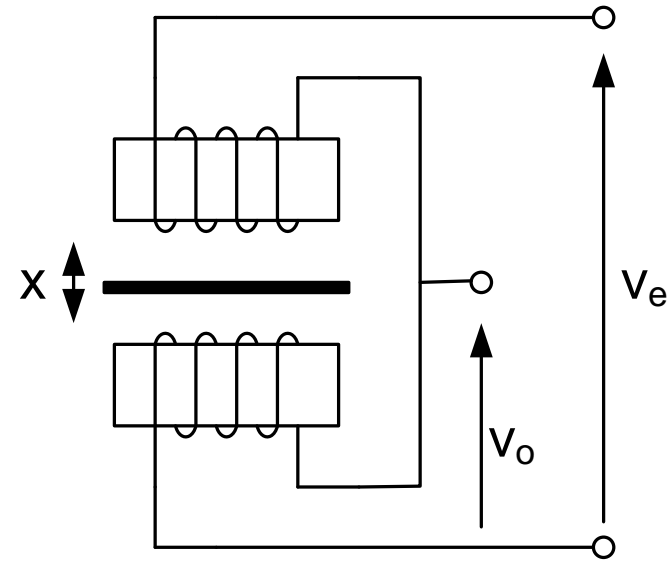
- two coils in series, moving object
  - increases reluctance in one coil
  - decreases reluctance in other coil
- circuit is differential voltage divider
- impedance of coil is equal to

$$Z = j\omega L$$

$$\left. \begin{aligned} L &= \frac{N^2}{\mathfrak{R}} \\ \mathfrak{R} &= \frac{1}{\mu\mu_0} \frac{l}{A} \end{aligned} \right\} \Rightarrow Z = j\omega \frac{N^2}{\mathfrak{R}} = j\omega \frac{N^2 \mu\mu_0 A}{l}$$

- changing  $l$  with a relative amount  $x$

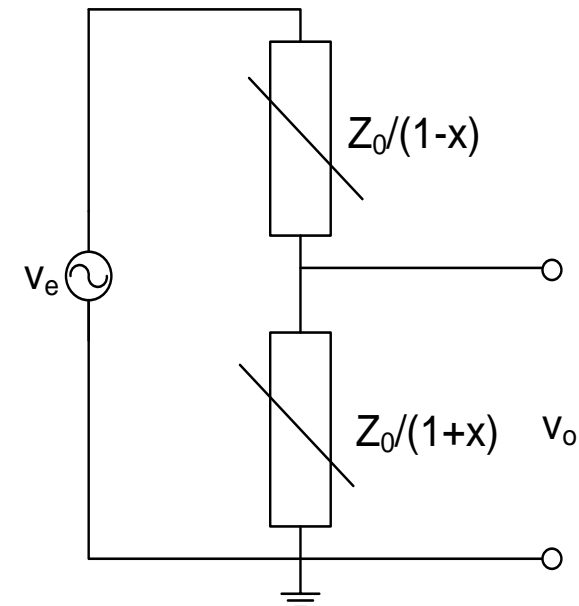
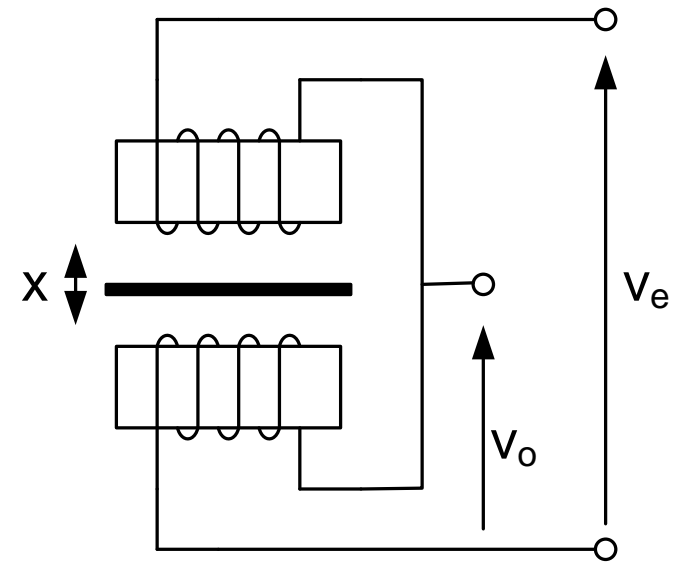
$$Z = j\omega \frac{N^2 \mu\mu_0 A}{l(1+x)} = \frac{j\omega L_0}{(1+x)} = \frac{Z_0}{(1+x)}$$



- two coils in series, moving object
  - increases reluctance in one coil
  - decreases reluctance in other coil
- circuit is differential voltage divider
- output of the voltage divider

$$v_o = \frac{Z_0/(1+x)}{Z_0/(1-x) + Z_0/(1+x)} v_e = \frac{1-x}{2} v_e$$

- linear relation between output voltage and displacement
- offset voltage present
- displacement ( $x$ ) should be small
- sensor often not practical



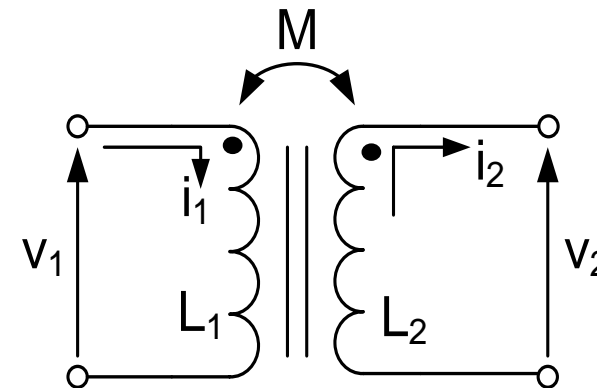
- self-inductance
  - induced voltage due to change in own current

$$v = L \frac{di}{dt}$$

- mutual inductance
  - induced voltage due to change in current in neighboring circuit

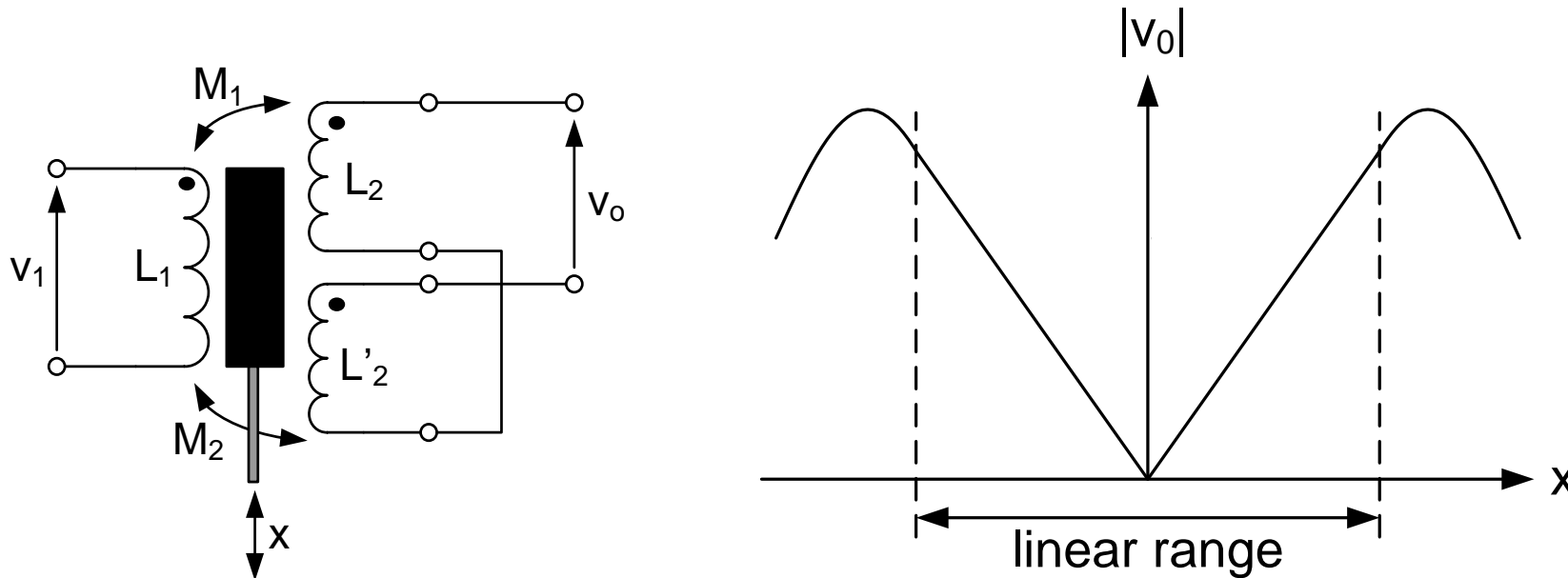
$$v_2 = L_2 \frac{di_2}{dt} - M \frac{di_1}{dt}$$

- depends on **reluctance** of the space between the coils
- changing reluctance between coils alters mutual inductance
  - device usable as sensor
  - two coil solution still not practical (large offset, small fluctuation)





- Linear Variable Differential Transformer (LVDT)
  - two secondary coils in series-opposition
  - linear relation between output voltage and core displacement
  - operation based on mutual inductance



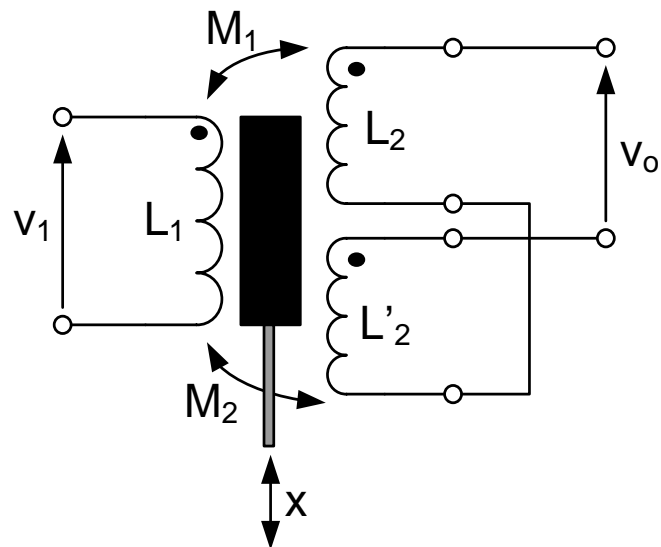
- assume sinusoidal excitation of primary circuit

$$v_1(t) = V_1 \sin(\omega t)$$

- output voltage of secondary circuit

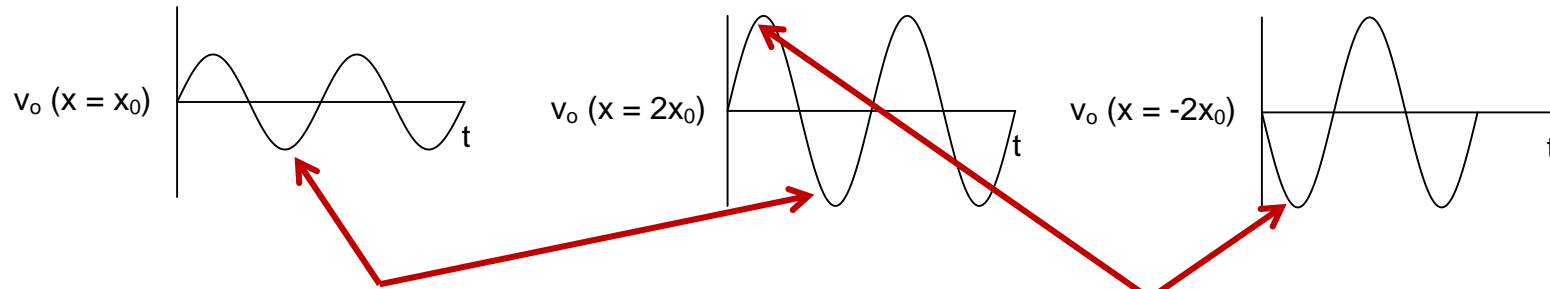
$$v_o(t) = S_\omega \cdot x \cdot V_1 \sin(\omega t + \phi)$$

- $S_\omega$  – sensitivity at frequency  $\omega$
- $x$  – displacement of the core from center
- $\phi$  – phase shift (in voltage) from primary to secondary circuit



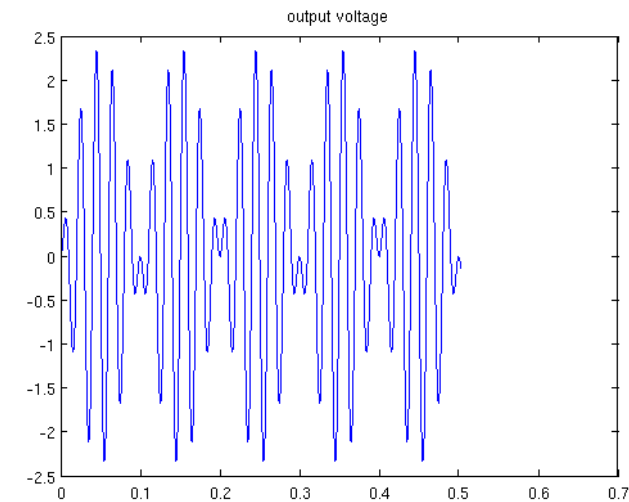
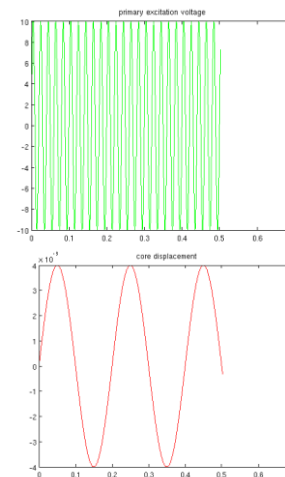
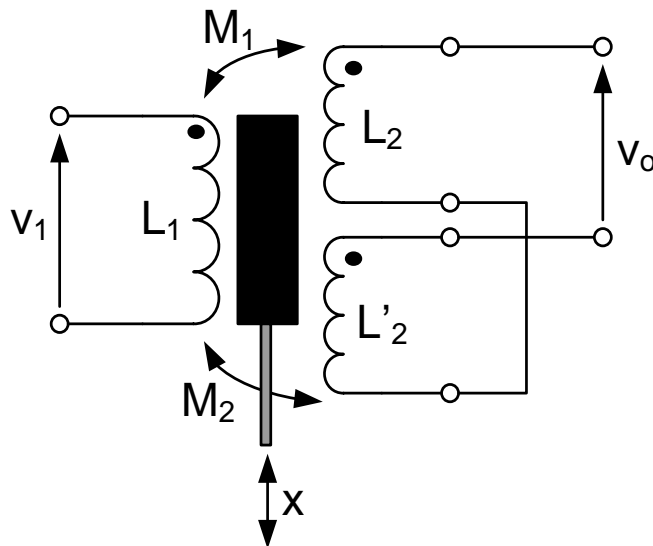
- $S_\omega$  and  $\phi$  depend on
  - load  $R_L$  of measurement circuit
  - excitation frequency  $\omega$
- phase shift can be compensated

- output signal of LVDT is amplitude modulated ac signal



amplitude indicates  
magnitude of  
displacement

phase indicates **direction** of  
displacement



- output voltage (no load connected to secondary winding)

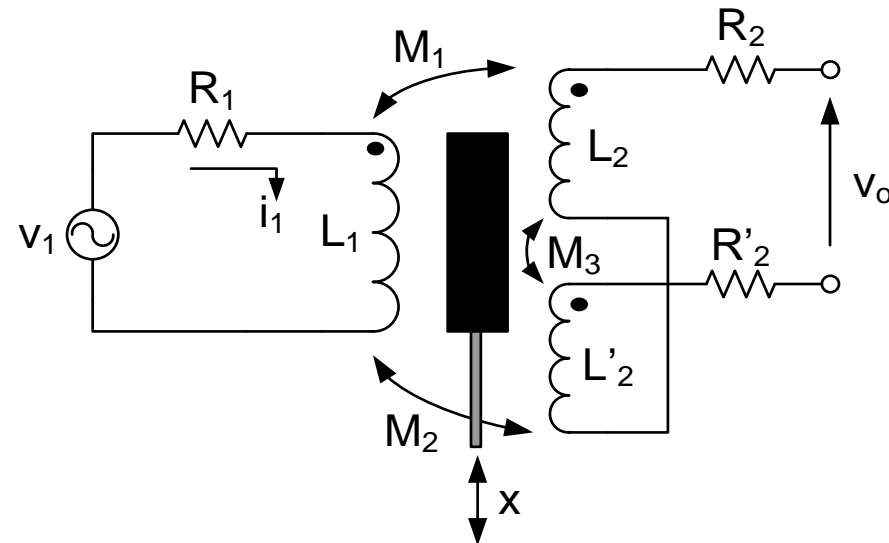
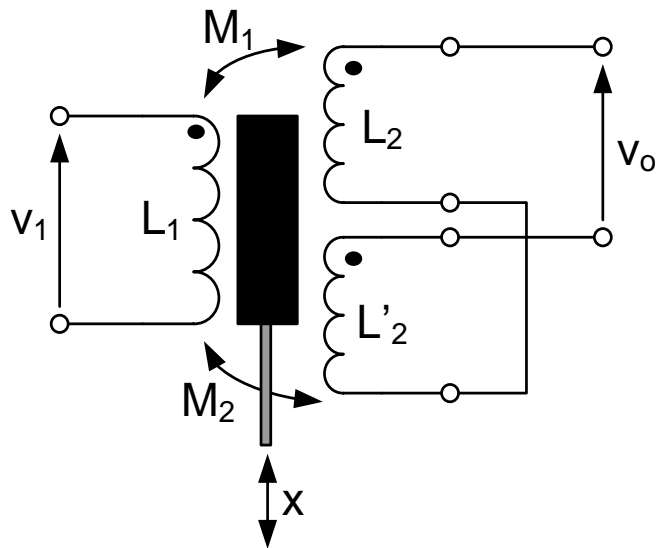
- no current in secondary circuit ( $I_2 = 0$ )

$$\left. \begin{aligned} V_1 &= I_1(R_1 + j\omega L_1) \Leftrightarrow I_1 = \frac{V_1}{j\omega L_1 + R_1} \\ V_o &= I_1(-j\omega M_1 + j\omega M_2) = j\omega(M_2 - M_1)I_1 \end{aligned} \right\} \Rightarrow V_o = \frac{j\omega(M_2 - M_1)V_1}{j\omega L_1 + R_1}$$

$$\left. \begin{aligned} & \\ & \end{aligned} \right\} \Rightarrow V_o = j\omega k_x x I_1 = \frac{j\omega k_x x V_1}{j\omega L_1 + R_1}$$

$(M_2 - M_1) = k_x x$

- primary current  $I_1$  independent of core position
- output voltage  $V_o$  proportional to core position



- output voltage (no load connected to secondary winding)

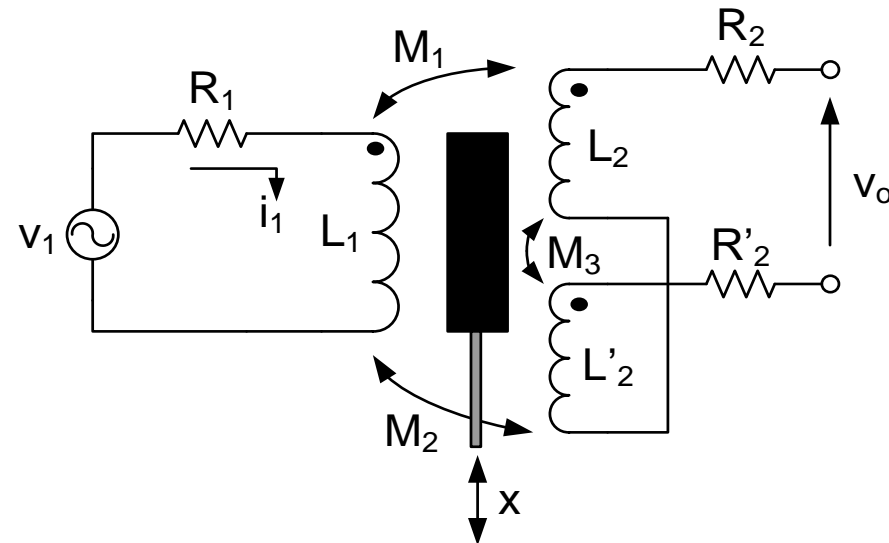
$$V_o = j\omega k_x x I_1 = \frac{j\omega k_x x V_1}{j\omega L_1 + R_1}$$

- sensitivity

$$S = \frac{|V_o/V_1|}{x} = \left| \frac{j\omega k_x}{j\omega L_1 + R_1} \right| = \left| \frac{k_x}{L_1 + \frac{R_1}{j\omega}} \right| = \left| \frac{k_x}{L_1 - j\frac{R_1}{\omega}} \right| = \frac{k_x}{\sqrt{L_1^2 + \frac{R_1^2}{\omega^2}}}$$

- sensitivity increases with increasing frequency
- phase shift
  - output voltage 90° out of phase
  - with primary current
  - phase shift between  $V_1$  and  $V_o$ 

$$\phi = 90^\circ - \arctan \frac{\omega L_1}{R_1}$$
- consider phase shift when recovering position





- output voltage (load  $R_L$  connected to secondary winding)

- output voltage

$$V_o = I_2 R_L$$

- current through secondary winding

- define total resistance in secondary windings as

$$R_{2c} = R_2 + R'_2 + R_L$$

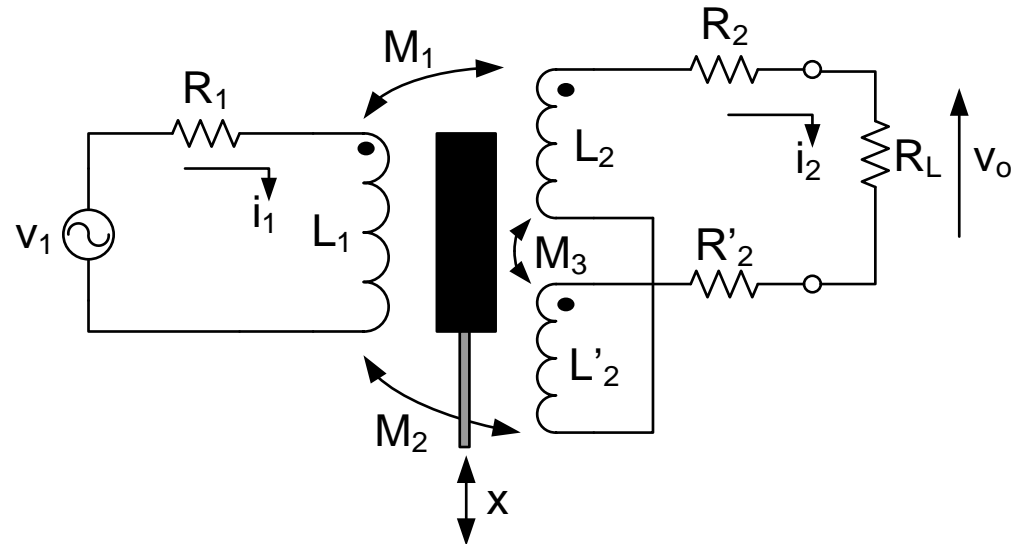
- no voltage source in secondary winding, thus holds

$$0 = I_1(-j\omega M_1 + j\omega M_2) + I_2(R_{2c} + j\omega L_2 + j\omega L'_2 - j\omega 2M_3)$$

$$\Leftrightarrow I_2 = \frac{-j\omega(M_2 - M_1)}{(R_{2c} + j\omega L_2 + j\omega L'_2 - j\omega 2M_3)} I_1$$

- $I_2$  depends on  $I_1$

$$\Leftrightarrow I_1 = \frac{(R_{2c} + j\omega L_2 + j\omega L'_2 - j\omega 2M_3)}{-j\omega(M_2 - M_1)} I_2$$



- output voltage (load  $R_L$  connected to secondary winding)

- output voltage

$$V_o = I_2 R_L$$

- $I_2$  depends on  $I_1$

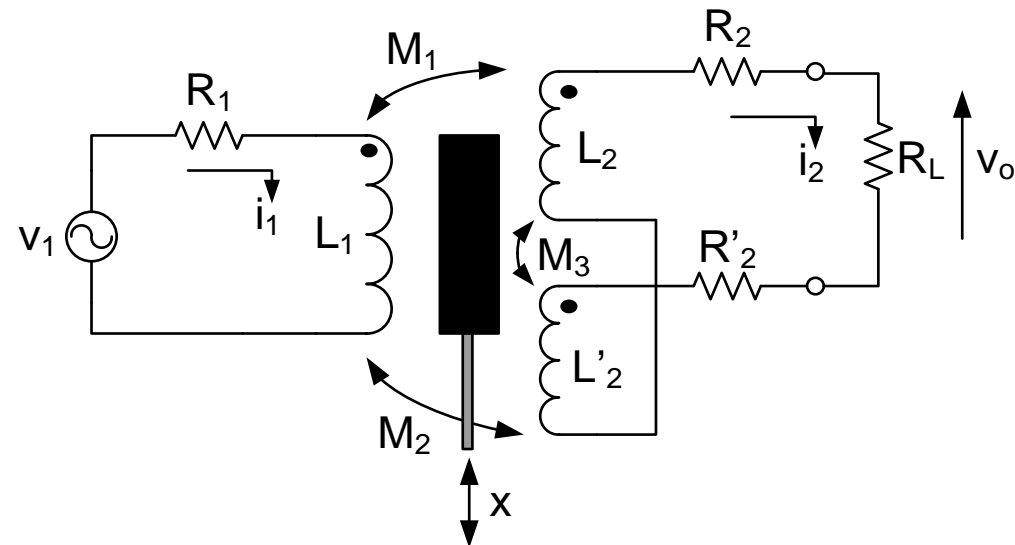
$$I_1 = \frac{(R_{2c} + j\omega L_2 + j\omega L'_2 - j\omega 2M_3)}{-j\omega(M_2 - M_1)} I_2$$

- current ( $I_1$ ) through primary winding

$$V_1 = I_1(R_1 + j\omega L_1) + I_2(-j\omega M_1 + j\omega M_2)$$

$$\Leftrightarrow I_1 = \frac{V_1 - j\omega(M_2 - M_1)I_2}{(R_1 + j\omega L_1)}$$

- $I_1$  equal in both
- expressions, hence ...



- output voltage (load  $R_L$  connected to secondary winding)

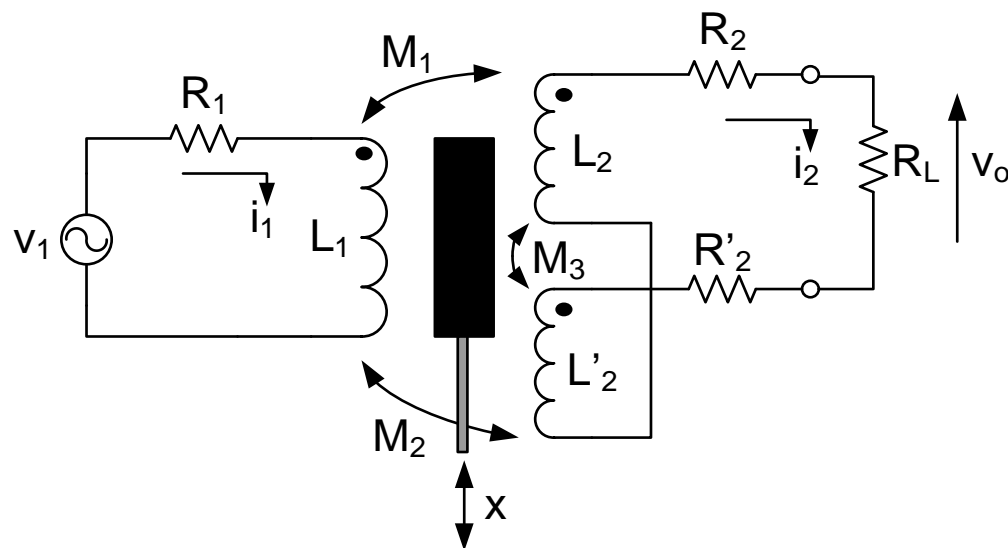
- output voltage

$$V_o = I_2 R_L$$

- $I_1$  equal in both expressions, hence ...

$$\frac{V_1 - j\omega(M_2 - M_1)I_2}{(R_1 + j\omega L_1)} = \frac{(R_{2c} + j\omega L_2 + j\omega L'_2 - j\omega 2M_3)I_2}{-j\omega(M_2 - M_1)}$$

$$\Rightarrow I_2 = \frac{j\omega(M_2 - M_1)V_1}{(j\omega)^2((M_2 - M_1)^2 - L_1(L_2 + L'_2 - 2M_3)) - j\omega(R_{2c}L_1 + R_1(L_2 + L'_2 - 2M_3)) - R_1R_{2c}}$$



- output voltage (load  $R_L$  connected to secondary winding)

$$V_o = \frac{j\omega(M_2 - M_1)R_L V_1}{(j\omega)^2((M_2 - M_1)^2 - L_1(L_2 + L'_2 - 2M_3)) - j\omega(R_{2c}L_1 + R_1(L_2 + L'_2 - 2M_3)) - R_1R_{2c}}$$

- difference in mutual inductance related to core position

$$(M_2 - M_1) = k_x x$$

- output voltage in terms of core position

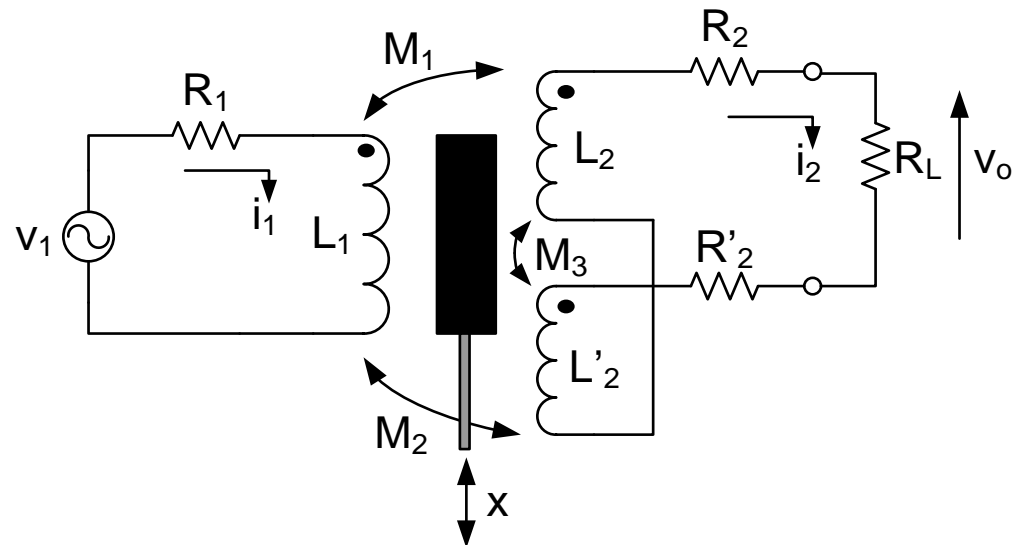
$$V_o = \frac{j\omega k_x x R_L V_1}{(j\omega)^2((k_x x)^2 - L_1(L_2 + L'_2 - 2M_3)) - j\omega(R_{2c}L_1 + R_1(L_2 + L'_2 - 2M_3)) - R_1R_{2c}}$$

- $V_o = 0$  when  $M_1 = M_2$  (core in center)

- it holds that

$$L_1(L_2 + L'_2 - 2M_3) \gg (k_x x)^2$$

- $V_o$  changes linearly on both sides of center



- output voltage (load  $R_L$  connected to secondary winding)

$$V_o = \frac{j\omega k_x x R_L V_1}{(j\omega)^2 ((k_x x)^2 - L_1(L_2 + L'_2 - 2M_3)) - j\omega(R_{2c}L_1 + R_1(L_2 + L'_2 - 2M_3)) - R_1R_{2c}}$$

- it holds that

$$L_1(L_2 + L'_2 - 2M_3) \gg (k_x x)^2$$

$$L_2 + L'_2 - 2M_3 \approx 2L_2$$

- hence

$$V_o = \frac{j\omega k_x x V_1 R_L}{-(j\omega)^2 2L_1L_2 - j\omega(R_{2c}L_1 + 2R_1L_2) - R_1R_{2c}}$$

- sensitivity

$$S = \frac{|V_o/V_1|}{x} = \frac{\omega k_x R_L}{\sqrt{(R_1R_{2c} - \omega^2 2L_1L_2)^2 + \omega^2 (R_{2c}L_1 + 2R_1L_2)^2}}$$

- sensitivity increases with  $R_L$  (up-to some frequency)
- sensitivity depends on excitation frequency of primary circuit



- output voltage (load  $R_L$  connected to secondary winding)

$$V_o = \frac{j\omega k_x x V_1 R_L}{-(j\omega)^2 2L_1 L_2 - j\omega(R_{2c}L_1 + 2R_1L_2) - R_1R_{2c}}$$

- (in general) phase difference between  $V_1$  and  $V_o$
- no phase shift when

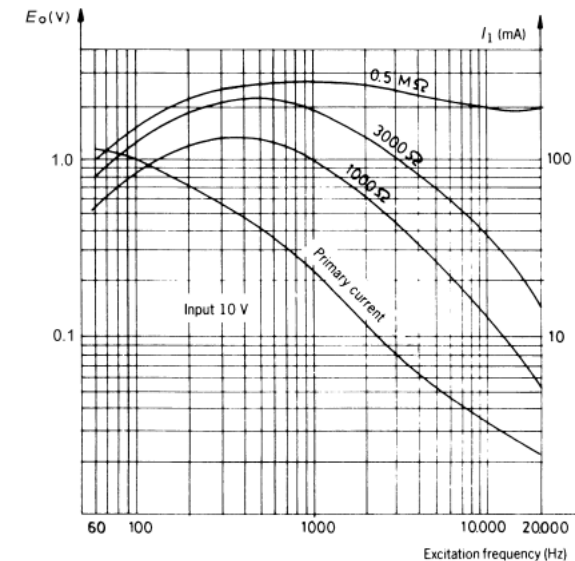
$$(j\omega)^2 2L_1 L_2 + R_1 R_{2c} = 0$$

$$\Leftrightarrow (j2\pi f_n)^2 2L_1 L_2 + R_1 R_{2c} = 0 \Leftrightarrow -(2\pi f_n)^2 2L_1 L_2 + R_1 R_{2c} = 0 \Rightarrow f_n = \frac{1}{2\pi} \sqrt{\frac{R_1 R_{2c}}{2L_1 L_2}}$$

- sensitivity at frequency  $f_n$

$$S = \left. \frac{|V_o/V_1|}{x} \right|_{\omega=2\pi f_n} = \frac{k_x R_L}{\sqrt{(R_{2c}L_1 + 2R_1L_2)^2}} = \frac{k_x R_L}{R_{2c}L_1 + 2R_1L_2}$$

- sensitivity increases with  $R_L$
- any other frequency has lower sensitivity for same  $R_L$



## example – sensitivity of an LVDT

- primary winding has a dc resistance of  $67 \Omega$
- two series-opposition windings have a total dc resistance of  $2800 \Omega$
- at 1kHz
  - primary winding has impedance of  $290 \Omega$
  - secondary windings have impedance of  $4800 \Omega$
  - sensitivity (normalized to excitation voltage) is  $270 (\mu\text{V}/\text{V})/\mu\text{m}$
- **calculate the following**
  - inductance of primary and secondary winding
  - excitation frequency that yields zero phase shift between primary and secondary voltage with load resistance of  $10 \text{ k}\Omega$
  - normalized sensitivity when the LVDT is excited at 60 Hz and the load resistance is equal to  $500 \text{ k}\Omega$
  - normalized sensitivity when the LVDT is excited at 60 Hz and the load resistance is equal to  $10 \text{ k}\Omega$

example – sensitivity of an LVDT

calculate the inductance of primary and secondary winding

- primary winding

$$|Z_1| = \sqrt{R_1^2 + (2\pi f L_1)^2}$$

$$L_1 = \frac{\sqrt{|Z_1|^2 - R_1^2}}{2\pi f} = \frac{\sqrt{(290\Omega)^2 - (67\Omega)^2}}{2\pi(1000\text{Hz})} = 45\text{mH}$$

- secondary winding

$$L_2 = \frac{1}{2} \frac{\sqrt{|Z_2|^2 - (R_2 + R'_2)^2}}{2\pi f} = \frac{1}{2} \frac{\sqrt{(4800\Omega)^2 - (2800\Omega)^2}}{2\pi(1000\text{Hz})} = 310\text{mH}$$

calculate the excitation frequency that yields zero phase shift with 10 kΩ load resistance

$$f_n = \frac{1}{2\pi} \sqrt{\frac{R_1 R_{2c}}{2L_1 L_2}} = \frac{1}{2\pi} \sqrt{\frac{(67\Omega)(2800\Omega + 10\text{k}\Omega)}{2(45\text{mH})(310\text{mH})}} = 882\text{Hz}$$

**example – sensitivity of an LVDT**

**calculate the normalized sensitivity when the LVDT is excited at 60 Hz and the load resistance is equal to 500 kΩ**

- secondary circuit assumed open when load resistance is 500kΩ
- use  $j\omega = j2\pi f$ ,  $|j\omega a + b| = \sqrt{\omega^2 a^2 + b^2}$
- sensitivity is equal to

$$S = \frac{|V_o/V_1|}{x} = \frac{2\pi f k_x}{\sqrt{R_1^2 + (2\pi f L_1)^2}}$$

- at 1kHz,  $S = 270\mu\text{V}/\text{V}/\mu\text{m}$

$$k_x = \frac{270 \cdot 10^{-6}}{10^{-6}\text{m}} \frac{\sqrt{R_1^2 + (2\pi f L_1)^2}}{2\pi f} = \frac{270}{1\text{m}} \frac{\sqrt{(67\Omega)^2 + (2\pi \times 1\text{kHz} \times 45\text{mH})^2}}{2\pi \times 1000\text{rad}} = 12.5(\Omega/\text{m})/(\text{rad}/\text{s})$$

- sensitivity at 60Hz is thus equal to

$$S = \frac{(2\pi \times 60\text{rad}) \times (12.5\Omega \cdot \text{s}/\text{m} \times \text{rad})}{\sqrt{(67)^2 + (2\pi \times 60\text{rad} \times 45\text{mH})^2}} = 68.2(\mu\text{V}/\text{V})/\mu\text{m}$$

example – sensitivity of an LVDT

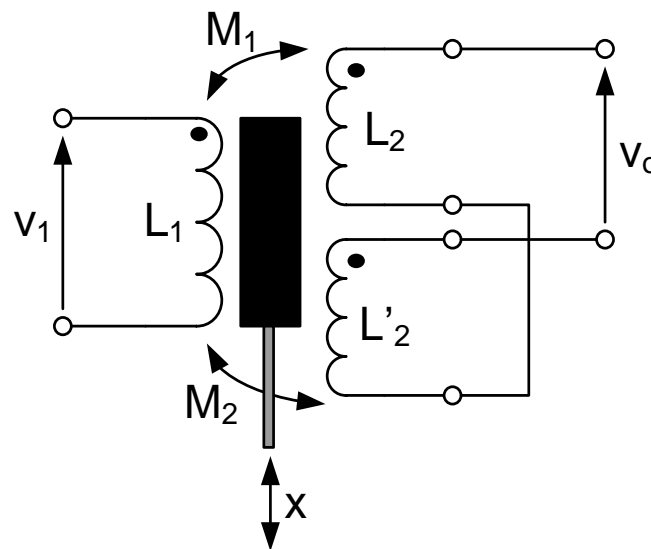
calculate the normalized sensitivity when the LVDT is excited at 60 Hz when the load resistance is equal to 10 kΩ

- secondary is loaded (not open) when load resistance is 10 kΩ
- we computed earlier

$$\begin{aligned}
 S &= \frac{|V_o/V_1|}{x} = \frac{\omega k_x R_L}{\sqrt{(R_1 R_{2c} - \omega^2 2L_1 L_2)^2 + \omega^2 (R_{2c} L_1 + 2R_1 L_2)^2}} \\
 &= \frac{(12.5\Omega \cdot s/m \times rad)(2\pi \times 60rad)(10k\Omega)}{\sqrt{((67\Omega)(12800\Omega) - (2\pi \times 60Hz)^2 2(45mH)(310mH))^2 + (2\pi \times 60Hz)^2 ((12800\Omega)(45mH) + 2(67\Omega)(310mH))^2}} \\
 &= 53.3(\mu V/V)/\mu m
 \end{aligned}$$



- assume sinusoidal excitation of primary circuit
  - $v_1(t) = V_1 \sin(\omega t)$
- output voltage of secondary circuit
  - $v_o(t) = S_\omega \cdot x \cdot V_1 \sin(\omega t + \phi)$ 
    - $S_\omega$  – sensitivity at frequency  $\omega$
    - $x$  – displacement of the core from center
    - $\phi$  – phase shift (in voltage) from primary to secondary circuit
- $S_\omega$  and  $\phi$  depend on
  - load  $R_L$  of measurement circuit
  - excitation frequency  $\omega$
- phase shift can be compensated



- output signal of LVDT is amplitude modulated ac signal

